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| APPLICATION NO.                               | FILING DATE   | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO.     | CONFIRMATION NO.        |  |  |
|---|---------------|----------------------|-------------------------|-------------------------|--|--|
| 10/775,122                                    | 02/11/2004    | Taiji Noda           | 60188-766               | 60188-766 2607          |  |  |
| 75  | 90 08/09/2005 | EXAM                 | EXAMINER                |                         |  |  |
| Jack Q. Lever, Jr.<br>McDERMOTT, WILL & EMERY |               |                      | LEE, CH                 | LEE, CHEUNG             |  |  |
| 600 Thirteenth                                |               | ART UNIT             | PAPER NUMBER            |                         |  |  |
| Washington, DC 20005-3096                     |               |                      | 2812                    | 2812                    |  |  |
|   |               |                      | DATE MAILED: 08/09/2009 | DATE MAILED: 08/09/2005 |  |  |

Please find below and/or attached an Office communication concerning this application or proceeding.

| Office Action Summary  Examiner Cheung Lee 2812  The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply  A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.  - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).  Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).   |  |  | Application  | on No.  | Applicant(s)   |              |  |  |  |
|--|--|--|--|---|--|--------------|--|--|--|
| Cheung Lee 2812  - The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply  A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.  If the MAILING DATE OF THIS COMMUNICATION.  If the period for reply specified above is less than they (30) days, a reply within the statutory minorium of thirty (30) days with be considered finely.  If the period for reply specified above is less than they (30) days, a reply within the statutory minorium of thirty (30) days with be considered finely.  If the period for reply specified above is less than they (30) days, a reply within the statutory minorium of thirty (30) days with be considered finely.  If the period for reply specified above is less than they (30) days, and a reply with the considered finely.  If the period for reply specified above is less than they (30) days, and a reply with the considered finely.  If the period for reply specified above is less than they (30) days, and a reply with the considered finely.  If the period for reply specified above is less than they (30) days and the period for reply specified above is less than they (30) days and the period of the    |  |  |  |   |  | and          |  |  |  |
| The MAILING DATE of this communication appears on the cover sheet with the correspondence address — Period for Reply  A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.  Extentions of them really be willing the control of the state of the provision of 37 CPR 1.79(4), in no event, however, may a reply be timely tited.  Extentions of the reply appealed above is less than thirty (30) days, a neply which the statutory minimum of thirty (40) days will be considered timely.  If the period for reply specified above is less than thirty (30) days, a neply which the statutory minimum of thirty (40) days will be considered timely.  If the period for reply specified above is less than thirty (30) days, a neply which the statutory minimum of the part of the reply which is set or externed period for reply will, by statuto, cause the application to become ABANDONED (53 U.S.C. § 133), asked to reply which is set of externed period for reply will, by statutory and the reply and will expect \$20,000 the control of the communication.  Finally be set of the communication of the communication, even if timely flex, may reduce they extend a place of this communication, even if timely flex, may reduce they extend a place of this communication, even if timely flex, may reduce they extend a place of the communication is provided to the communication.  1) ☐ Responsive to communication(s) filed on 66 June 2005.  2a) ☐ This action is FINAL.  2b) ☐ Claim(s) 1-14 is/are pending in the application.  4) ☐ Claim(s) 1-14 is/are replected.  2) ☐ Claim(s) 1-14 is/are rejected.  3) ☐ Claim(s) 1-14 is/are rejected.  3) ☐ Claim(s) 1-14 is/are rejected.  3) ☐ Claim(s) 1-14 is/are rejected.  4) ☐ Claim(s) 1-16 is/are allowed.  4pplication Papers  9) ☐ The specification is objected to by the Examiner.  4pplication Papers  9) ☐ The specification is objected to by the Examiner.  10) ☐ The dath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.  Priori |  | Office Action Summary  | Examiner   |   | Art Unit   |              |  |  |  |
| A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.  **Stateshible of three may be available under the provisions of 37 CFR 1.35(a). In no event, however, may a reply be timely filed attachment of the provision of 17 CFR 1.35(a). In no event, however, may a reply be timely filed attachment of the provision of 17 CFR 1.35(a) and the statutory minimum of thirty (30) days will be considered timely.  **If NO period for regly is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the making date of this communication. Provision for specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the making date of this communication. Provision for specified above, the maximum statutory and the specified before ARAMONDED (30 LS C) 3130.  **Status**  1) Since this application is no condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under Ex parte Queyle, 1935 C.D. 11, 453 O.G. 213.  Disposition of Claims  4) Claim(s) 1-14 is/are pending in the application.  4a) Of the above claim(s) 15 is/are withdrawn from consideration.  5) Claim(s) 1-16 is/are allowed.  5) Claim(s) 1-16 is/are rejected.  7) Claim(s) is/are allowed.  6) Claim(s) 1-16 is/are rejected to by the Examiner.  Application Papers  9) The specification is objected to by the Examiner.  10) The drawing(s) filed on 11 February 2004 is/are: a) accepted or b) objected to by the Examiner.  Application Papers  9) The specification is objected to by the Examiner.  11) The oath or declaration is objected to by the Examiner.  Application from the question is objected to by the Examiner.  Application from the objected to by the Examiner. Note the attached Office Action or form PTO-152.  Priority under 35 U.S.C. § 119  12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).  a) All b) Some** c) None of:  1. Certified copies of the pri |  |  | Cheung Le  | e   | 2812   |              |  |  |  |
| A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.  Eadminstor of them may be available unified the provisions of 3 CPR 1.103(s), in no event, however, may a reply be timely filed Eadminstor of the reply specified above is lists than thirty (30) days, a neply which has distulatory minimum of thirty (30) days, a reply which has distulatory minimum of thirty (30) days, a neply which has distulatory minimum of thirty (30) days, a neply which has distulated or reply specified above is lists than thirty (30) days, a neply which has distulated the replaced of replaced of the replaced of the replaced of the replaced of the r |  |  | cation appears on the  | cover sheet with the  | correspondence add   | ress         |  |  |  |
| Extensions of time may be available under the provisions of 37 CFR. 1.19(d). In no event, however, may a raply be timely filled after Str. (g) MONTHS from the mailing date of this commissions.  If NO period for reply is called a time, the main main main control of the provisions of the commissions of the commission   | A SH   | ORTENED STATUTORY PERIOD FO  |  | O EXPIRE <u>3</u> MONTH   | H(S) FROM  |              |  |  |  |
| 1)⊠ Responsive to communication(s) filed on @6_June_2005. 2a)□ This action is FINAL. 2b)⊠ This action is non-final. 3)□ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.  Disposition of Claims 4 ○ Claim(s)  | - Exte<br>after<br>- If the<br>- If NC<br>- Failu<br>Any | nsions of time may be available under the provisions of SIX (6) MONTHS from the mailing date of this commusive period for reply specified above is less than thirty (30) period for reply is specified above, the maximum state to reply within the set or extended period for reply reply received by the Office later than three months af | of 37 CFR 1.136(a). In no eve<br>unication.<br>) days, a reply within the statu<br>tutory period will apply and wil<br>vill, by statute, cause the appli | atory minimum of thirty (30) d<br>Il expire SIX (6) MONTHS fro<br>ication to become ABANDON | ays will be considered timely. on the mailing date of this corr NED (35 U.S.C. § 133). | nmunication. |  |  |  |
| 2a)  This action is FINAL. 2b)  This action is non-final.  3   Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.  Disposition of Claims  4)  Claim(s) 1.14 is/are pending in the application. 4a) Of the above claim(s) 1.5 is/are withdrawn from consideration.  5)  Claim(s)  is/are allowed. 6)  Claim(s)  is/are objected to. 8)  Claim(s)  is/are objected to. 8)  Claim(s)  is/are objected to. 9)  The specification is objected to by the Examiner.  10)  The drawing(s) filed on 11 February 2004 is/are: a)  accepted or b)  objected to by the Examiner. Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a). Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 OFR 1.121(d).  11)  The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.  Priority under 35 U.S.C. § 119  12)  Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a)  All b)  Some c) None of: 1   Certified copies of the priority documents have been received in Application No. 3   Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).  *See the attached detailed Office action for a list of the certified copies not received.  Attachment(s)  1)  Notice of References Cited (PTO-892) Chall Notice of References Cited (PTO-892) Chall Notice of Informal Patent Application (PTO-152)  | Status   |  |  |   |  |              |  |  |  |
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| closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.  Disposition of Claims  4)   |  | · ·  |  | on-final.   | •  |              |  |  |  |
| 4)  Claim(s) 1-14 is/are pending in the application. 4a) Of the above claim(s) 15 is/are withdrawn from consideration.  5)  Claim(s)  is/are allowed. 6)  Claim(s) 1-14 is/are rejected. 7)  Claim(s)  is/are objected to. 8)  Claim(s)  is/are objected to. 8)  Claim(s)  is/are objected to restriction and/or election requirement.  Application Papers  9)  The specification is objected to by the Examiner. 10)  The drawing(s) filed on 11 February 2004 is/are: a)  accepted or b)  objected to by the Examiner. Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a). Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d). 11)  The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.  Priority under 35 U.S.C. § 119  12)  Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a)  All b)  Some * c)  None of:  1.  Certified copies of the priority documents have been received. 2.  Certified copies of the priority documents have been received in Application No. 3.  Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.  Attachment(s)  1) Notice of References Cited (PTO-892)  Notice of References Cited (PTO-149) or PTO/SB/08) Notice of Uniformal Patent Application (PTO-152)  | 3)□  |  |  |   |  |              |  |  |  |
| 4a) Of the above claim(s) 15 is/are withdrawn from consideration.  5) ☐ Claim(s)   | Disposit   | ion of Claims  |  |   |  |              |  |  |  |
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| Application Papers  9) ☐ The specification is objected to by the Examiner.  10) ☒ The drawing(s) filed on 11 February 2004 is/are: a) ☒ accepted or b) ☐ objected to by the Examiner.  Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).  Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).  11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.  Priority under 35 U.S.C. § 119  12) ☒ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).  a) ☒ All b) ☐ Some * c) ☐ None of:  1. ☒ Certified copies of the priority documents have been received.  2. ☐ Certified copies of the priority documents have been received in Application No. ☐  3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).  * See the attached detailed Office action for a list of the certified copies not received.  Attachment(s)  1) ☒ Notice of References Cited (PTO-892)  ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948)  3) ☒ Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)  5) ☐ Notice of Informal Patent Application (PTO-152)   | 7)   | 7) Claim(s) is/are objected to.  |  |   |  |              |  |  |  |
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| 10) ☐ The drawing(s) filed on 11 February 2004 is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.  Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).  Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).  11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.  Priority under 35 U.S.C. § 119  12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).  a) ☐ All b) ☐ Some * c) ☐ None of:  1. ☐ Certified copies of the priority documents have been received.  2. ☐ Certified copies of the priority documents have been received in Application No.  3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).  * See the attached detailed Office action for a list of the certified copies not received.  Attachment(s)  1) ☐ Notice of References Cited (PTO-892)  2) ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948)  3) ☐ Interview Summary (PTO-413)  Paper No(s)/Mail Date.  Paper No(s)/Mail Date.  Paper No(s)/Mail Date.  Paper No(s)/Mail Date.  Notice of Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)   | Applicat   | ion Papers   |  |   | •  |              |  |  |  |
| Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).  Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).  11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.  Priority under 35 U.S.C. § 119  12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).  a) All b) Some * c) None of:  1. Certified copies of the priority documents have been received.  2. Certified copies of the priority documents have been received in Application No.  3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).  * See the attached detailed Office action for a list of the certified copies not received.  Attachment(s)  1) Notice of References Cited (PTO-892)  Notice of Draftsperson's Patent Drawing Review (PTO-948)  3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)  Notice of Informal Patent Application (PTO-152)   | 9)[  | The specification is objected to by the  | Examiner.  |   |  |              |  |  |  |
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| a)   | Priority (   | under 35 U.S.C. § 119  |  |   |  |              |  |  |  |
| a)   | 12)🖂   | Acknowledgment is made of a claim f  | or foreign priority und  | der 35 U.S.C. § 119(  | (a)-(d) or (f).  |              |  |  |  |
| 2. ☐ Certified copies of the priority documents have been received in Application No  3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).  * See the attached detailed Office action for a list of the certified copies not received.  Attachment(s)  1) ☑ Notice of References Cited (PTO-892)  2) ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948)  3) ☑ Information Disclosure Statement(ş) (PTQ-1449 or PTO/SB/08)  5) ☐ Notice of Informal Patent Application (PTO-152)   |  |  |  |   |  |              |  |  |  |
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| 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)  3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)  Paper No(s)/Mail Date  Notice of Informal Patent Application (PTO-152)  |  | • •  | •  | 4) Interview Summa  | rv (PTO-413)   |              |  |  |  |
|  | 2) Notice  | e of Draftsperson's Patent Drawing Review (P   |  | Paper No(s)/Mail  | Date   | 4.           |  |  |  |
| •  | 3) 🔀 Infor<br>Pape                                       | mation Disclosure Statement(s) (PTO-1449 or Fer No(s)/Mail Date <u>02/11/04</u> . / 06/13/05   | PTO/SB/08)   | -   | I Patent Application (PTO-   | 152)         |  |  |  |

## **DETAILED ACTION**

## Election/Restrictions

Applicant's election of claims 1-14 in the reply filed on June 6, 2005 is acknowledged.

#### Information Disclosure Statement

The information disclosure statement (IDS) submitted on June 13, 2005 was filed before the first action on the merits. The submission is in compliance with the provisions of 37 CFR 1.97. Accordingly, the information disclosure statement is being considered by the examiner.

# Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 1. Claims 1-14 are rejected under 35 U.S.C. 103(a) as being obvious over Noda et al. (U.S. Patent 6,432,802; hereinafter "Noda") in view of Jain et al. (U.S. Patent 6,808,997; hereinafter "Jain").
- 2. With respect to claim 1, Noda discloses a fabrication method for a semiconductor device comprising the steps of: (a) forming a gate electrode (col. 6, lines 55-59; fig. 1(b), item 102) on a semiconductor region of a first conductivity type (col. 6, lines 41-54) with

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a gate insulating film interposed therebetween (col. 6 lines 55-59; fig. 1(b), item 101); (b) forming extension implanted layers in the semiconductor region by implanting first impurities of a second conductivity type in the semiconductor region using the gate electrode as a mask (col. 6, lines 60-67 and col. 7, lines 1-4); and (d), forming extension diffused layers of the second conductivity type made from diffusion of the first impurities in top portions of the semiconductor region (fig. 2(a), item 105) by performing first heat treatment (col. 7, lines 16-37). However, Noda does not disclose expressly a step (c), after the step (b), forming fluorine implanted layers in the semiconductor region by implanting fluorine in the semiconductor region using the gate electrode as a mask.

Jain teaches a method for forming ultra shallow junction in semiconductor substrates using multiple ion implantation steps including fluorine implantation (col. 6, lines 55-67 and col. 7, lines 1-22). Also, Jain discloses that fluorine implantation steps can be performed after the primary dopant implantation (col. 9, lines 16-42).

The examiner takes the position that it is obvious to use the gate electrode as a mask during the fluorine implantation since Noda uses the gate electrode as a mask during the first implantation (col. 6, lines 60-67).

At the time of the invention it would have been obvious to a person of ordinary skill in the art to use a fluorine implanted layer in the semiconductor region to form welldefined shallow junctions semiconductor device, as taught by Jain. The motivation for doing so would have been to achieve reduction of the effects of dopant channeling and diffusion (col. 3, lines 61-67 and col. 4, lines 1-8).

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3. With respect to claim 2, Noda discloses a fabrication method for a semiconductor device as set forth in claim 1, but Noda does not disclose expressly the dose of fluorine in the step (c) is not less than 1x10<sup>13</sup>/cm<sup>2</sup> and also in the level at which the semiconductor region is kept from becoming amorphous.

Jain discloses the fluorine implantation as described in claim 1, and also discloses the preferable fluorine dose, which is between about 1x10<sup>13</sup> cm<sup>-2</sup> and about 1x10<sup>15</sup> cm<sup>-2</sup> (col. 7, lines 55-67). Also, Jain mentions that the invention employs a crystalline semiconductor substrate (col. 5, lines 54-65). At least at the lower range of the dose of fluorine is in the level at which the semiconductor region is kept from becoming amorphous.

4. With respect to claim 3, Noda discloses a fabrication method for a semiconductor device as set forth in claim 1, but Noda does not disclose expressly the dose of fluorine in the step (c) is less than  $3x10^{14}$ /cm<sup>2</sup>.

Jain discloses the preferable dose of junction narrowing species, which is between about  $1x10^{13}$  cm<sup>-2</sup> and about  $1x10^{15}$  cm<sup>-2</sup> (col. 7, lines 55-67). Therefore, this claim limitation is met whenever the dose of junction narrowing species is between about  $1x10^{13}$  cm<sup>-2</sup> and about  $3x10^{14}$  cm<sup>-2</sup>.

5. With respect to claim 4, Noda discloses a fabrication method for a semiconductor device as set forth in claim 1, wherein the implantation projected range of fluorine in the step (c) is roughly the same as the implantation projected range of the first impurities in the step (b). Noda discloses the p-type and n-type dopant doses (col. 6, lines 60-67 and col. 7, lines 1-4), which are within the fluorine dose range as set forth in claim 3.

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6. With respect to claim 5, Noda discloses a fabrication method for a semiconductor device as set forth in claim 1, wherein the step (b) includes the step of forming pocket implanted layers in the semiconductor region (fig. 1(c), item 106A) by implanting second impurities of the first conductivity type in the semiconductor region (col. 7, lines 5-15) using the gate electrode as a mask, and in the step (d), pocket diffused layers of the first conductivity type made from diffusion of the second impurities (fig. 2(a), item 106) are formed in portions of the semiconductor region under the extension diffused layers (fig. 2(a), item 105) by performing the first heat treatment (col. 7, lines 16-37).

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- 7. With respect to claim 6, Noda discloses a fabrication method for a semiconductor device as set forth in claim 1, wherein after the step (d), the method further comprises the steps of: (e) forming sidewalls (fig. 2(b), item 107) made of an insulating film on walls of the gate electrode (col. 7, lines 37-44); (f) forming source/drain implanted layers in the semiconductor region by implanting third impurities of the second conductivity type in the semiconductor region using the gate electrode and the sidewalls as a mask (col. 7, lines 45-58); and (g) after the step (f), forming source/drain diffused layers of the second conductivity type made from diffusion of the third impurities (fig. 2(c), item 104) in portions of the semiconductor region on the outer sides of the sidewall (col. 7, lines 45-58).
- 8. With respect to claim 7, Noda discloses a fabrication method for a semiconductor device as set forth in claim 1, wherein in the step (d), the fluorine in the fluorine implanted layers diffuses while interacting with point defects, so that excessive point defects induced in the semiconductor region are removed.

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According to Noda, the transient enhanced diffusion (hereinafter "TED") is a phenomenon causes by point defects, existing in excessive numbers between lattice sites (col. 2, lines 29-36). Also, Jain discloses the presence of oxygen and interstitial defects in the semiconductor substrate can enhance the rate of diffusion of the dopant (col. 6, lines 20-25). Jain teaches that the TED further increases the junction broadening observed from annealing, and the fluorine function is to mitigate the junction broadening (col. 6, lines 55-67) thereby reduces dopant channeling and diffusion. Therefore, the examiner takes the position that it is inherent that the step of fluorine diffusion exists to remove the excessive point defects induced in the semiconductor region.

9. With respect to claim 8, Noda discloses a fabrication method for a semiconductor device as set forth in claim 1, further comprising the step of: performing extremely low temperature heat treatment for the semiconductor region before the step (d) and after the step (c), to recover crystal damage produced in the semiconductor region due to the implantation of the first impurities (col. 7, lines 16-37; col. 8, lines 25-30) and the fluorine without substantially allowing diffusion of the first impurities in the extension implanted layers.

According to Jain, fluorine implanted layer forms after the deposition of the first dopant and before the heat treatment, so it would have been obvious that the low temperature heat treatment is performed after the implantation of fluorine. Also, according to Noda, another annealing process is conducted with an elevated temperature after low temperature heat treatment, and this heat treatment is carried out

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to form the dopant diffused layers (col. 8, lines 25-33). So, the examiner takes the position that it would have been obvious that the step of extremely low temperature heat treatment is performed without substantially allowing diffusion of the first impurities.

- 10. With respect to claim 9, Noda discloses a fabrication method for a semiconductor device as set forth in claim 8, wherein the extremely low temperature heat treatment has a heating temperature of 400° C to 600° C (col. 7, lines 16-21).
- 11. With respect to claim 10, Noda discloses a fabrication method for a semiconductor device as set forth in claim 1, wherein the first heat treatment in the step (d) is rapid thermal annealing in which the temperature rise rate is about 100° C/s or more (col. 7, lines 20-30), the heating temperature is about 850° C to 1050° C (col. 7, lines 20-30), and the peak temperature is held for about ten seconds at the longest or is not held at all (col. 7, lines 20-30), however, Noda does not disclose expressly that the temperature drop rate is about 80° C/s or more.

Similar to the claimed invention, Noda discloses the heat treatment is carried out to form the extended high-concentration dopant diffused layer and pocket dopant diffused layer with similar heating temperature range and temperature rise rate (col. 8, lines 25-33), so the examiner takes the position that it would have been obvious that the temperature drop rate would be about 80° C/s.

12. With respect to claim 11, Noda discloses a fabrication method for a semiconductor device as set forth in claim 1, wherein the first impurities in the step (b) are boron or indium (col. 6, lines 60-67; col. 8, line 25).

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13. With respect to claim 12, Noda discloses a fabrication method for a semiconductor device as set forth in claim 1, wherein the first impurities in the step (b) are arsenic (col. 7, lines 1-4; col. 8, line 25).

14. With respect to claim 13, Noda discloses a fabrication method for a semiconductor device as set forth in claim 12, but Noda does not disclose expressly wherein during the first heat treatment in the step (d), the first impurities in the extension implanted layers diffuse in a state in which the fluorine has captured atomic vacancies produced in top portions of the semiconductor region.

Jain discloses the function of fluorine to an implantation process that deposits a primary dopant, which is allowing the formation of well-defined, ultra-shallow junction (col. 3, lines 61-67 and col. 4, lines 1-2). The fluorine implantation in Jain causes same results as the claimed steps of fluorine capturing atomic vacancies produced in top portions of the semiconductor region during the first impurities in the extension layer diffusion. The fluorine implantation suppresses the TED of the impurities and mitigates the junction broadening (col. 6, lines 55-67) thereby reduces dopant channeling and diffusion. Therefore, the examiner takes the position that the fluorine implantation process taught by Jain inherently performs the step of capturing atomic vacancies in top of the semiconductor region.

15. With respect to claim 14, Noda discloses a fabrication method for a semiconductor device as set forth in claim 1, wherein the dose for the implantation of the first impurities in the step (b) is in a level at which the semiconductor region is kept from becoming amorphous (col. 5, lines 29-42), and the extension diffused layers

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having a predetermined impurity concentration are formed by repeating a series of process steps composed of implanting the first impurities in the step (b) (col. 15, lines 33-45), and performing the first heat treatment in the step (d) (col. 15, lines 33-45).

Noda does not disclose expressly the fluorine implantation step. However, Jain discloses implanting the fluorine (col. 6, lines 55-67 and col. 7, lines 1-22) after the primary dopant implantation (col. 9, lines 16-42). So, the examiner takes the position that it would have been obvious that in the combined teaching of Noda and Jain the steps to form the extension diffused layers having predetermined impurity concentration by repeating step (b), (c), and (d) are performed.

At the time of the invention it would have been obvious to a person of ordinary skill in the art to use a fluorine implanted layer in the semiconductor region to form well-defined shallow junctions semiconductor device, as taught by Jain. The motivation for doing so would have been to achieve reduction of the effects of dopant channeling and diffusion (Jain, col. 3, lines 61-67 and col. 4, lines 1-8).

#### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Cheung Lee whose telephone number is 571-272-5977. The examiner can normally be reached on Monday through Friday from 8:30AM to 5:00 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Michael Lebentritt can be reached on 571-272-1873. The fax phone

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number for the organization where this application or proceeding is assigned is 571-273-8300.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Cheung Lee

August 5, 2005